

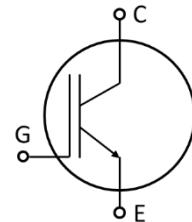
## IGBT Chip

### Features:

- 1200V Trench & Field stop technology
- Low Vcesat
- Positive temperature coefficient
- Easy paralleling

### Applications:

- High Power Converters
- Inverter



### Mechanical parameters

Die size	12.066 × 15.980	mm <sup>2</sup>
Emitter pad size	See chip drawing	
Gate pad size	1.22 × 0.77	
Area total	192.815	
Thickness	120	μm
Scribe line Size	80	
Wafer size	200	mm
Max. possible chips per wafer	127	
Passivation front side	Polyimide	
Pad metal	AlCu with Ti/TiN (5.0μm & 200A/700A)	
Backside metal	Al/Ti/Ni/Ag	

### Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-Emitter voltage	V <sub>CE</sub>	1200	V
DC collector current	I <sub>C</sub>	200	A
Operating junction temperature	T <sub>vj</sub>	-40 ~ 175	°C
Gate emitter voltage	V <sub>GE</sub>	±20	V

Short circuit data	t <sub>SC</sub>	10	μs
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**Static Characteristics** (tested on wafer), T<sub>vj</sub>=25°C

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Collector-Emitter breakdown voltage	V <sub>(BR)CES</sub>	V <sub>GE</sub> =0V, I <sub>C</sub> =1mA	1200			
Collector-Emitter saturation voltage	V <sub>CESat</sub>	V <sub>GE</sub> =15V, I <sub>C</sub> =200A		1.65	2.05	V
Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	I <sub>C</sub> =7.4mA, V <sub>GE</sub> = V <sub>CE</sub>	5.2	5.8	6.4	
Zero gate voltage collector current	I <sub>CES</sub>	V <sub>CE</sub> =1200V, V <sub>GE</sub> = 0V			10	uA
Gate-Emitter leakage current	I <sub>GES</sub>	V <sub>CE</sub> =0V, V <sub>GE</sub> = 20V			200	nA
Integrated gate resistor	r <sub>G</sub>			3.5		Ω
Input capacitance	C <sub>ies</sub>	V <sub>CE</sub> =25V, V <sub>GE</sub> =0V, f=100kHz		17.48		nF
Reverse transfer capacitance	C <sub>res</sub>			0.73		

#### Further Electrical Characteristic

Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

Application example	SF600R12D6
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**Chip Drawing**